

Features

- *Guaranteed* 4.5nV/ $\sqrt{\text{Hz}}$ 10Hz Noise
- *Guaranteed* 3.8nV/ $\sqrt{\text{Hz}}$ 1kHz Noise
- 0.1Hz to 10Hz Noise, 60nV_{P-P} Typical
- *Guaranteed* 7 Million Min Voltage Gain, $R_L = 2k$
- *Guaranteed* 3 Million Min Voltage Gain, $R_L = 600\Omega$
- *Guaranteed* 25 μV Max Offset Voltage
- *Guaranteed* 0.6 $\mu\text{V}/^\circ\text{C}$ Max Drift with Temperature
- *Guaranteed* 11V/ μs Min Slew Rate (FT1037)
- *Guaranteed* 117dB Min CMRR

Applications

- Low Noise Signal Processing
- Microvolt Accuracy Threshold Detection
- Strain Gauge Amplifiers
- Direct Coupled Audio Gain Stages
- Sine Wave Generators
- Tape Head Preamplifiers
- Microphone Preamplifiers

Description

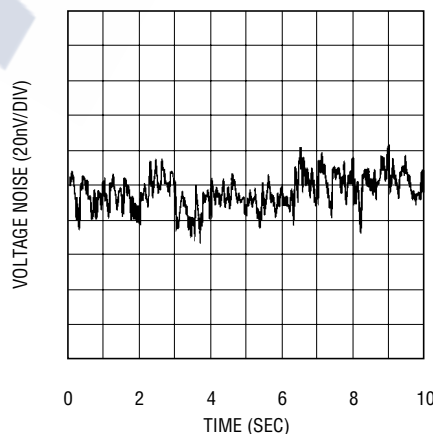
The FT1007/FT1037 series features the lowest noise performance available to date for monolithic operational amplifiers: 2.5nV/ $\sqrt{\text{Hz}}$ wideband noise (less than the noise of a 400 Ω resistor), 1/f corner frequency of 2Hz and 60nV peak-to-peak 0.1Hz to 10Hz noise. Low noise is combined with outstanding precision and speed specifications: 10 μV offset voltage, 0.2 $\mu\text{V}/^\circ\text{C}$ drift, 130dB common mode and power supply rejection, and 60MHz gain bandwidth product on the decompensated FT1037, which is stable for closed-loop gains of 5 or greater.

The voltage gain of the FT1007/FT1037 is an extremely high 20 million driving a 2k Ω load and 12 million driving a 600 Ω load to $\pm 10\text{V}$.

In the design, processing and testing of the device, particular attention has been paid to the optimisation of the entire distribution of several key parameters. Consequently, the specifications of even the lowest cost grades (the FT1007C and the FT1037C) have been spectacularly improved compared to equivalent grades of competing amplifiers.

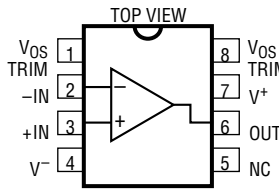
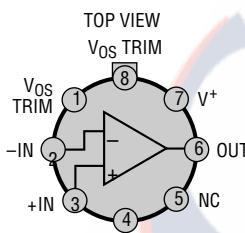
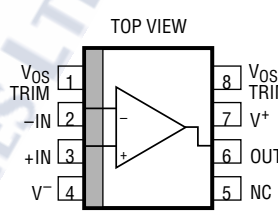
The sine wave generator application shown below utilises the low noise and low distortion characteristics of the FT1037.

0.1Hz to 10Hz Noise



Absolute Maximum Ratings (Note 1)

Supply Voltage	$\pm 22V$	Lead Temperature (Soldering, 10 sec.)	$300^{\circ}C$
Input Voltage	Equal to Supply Voltage	Operating Temperature Range	
Output Short-Circuit Duration	Indefinite	FT1007/FT1037AC, C	$0^{\circ}C$ to $70^{\circ}C$
Differential Input Current (Note 9)	$\pm 25mA$	FT1007/FT1037I	$-40^{\circ}C$ to $85^{\circ}C$
Storage Temperature Range	$-65^{\circ}C$ to $150^{\circ}C$	FT1007/FT1037AM, M	$-55^{\circ}C$ to $125^{\circ}C$

 N8 PACKAGE 8-LEAD PDIP $T_{JMAX} = 100^{\circ}C$, $\theta_{JA} = 130^{\circ}C/W$ (N8)	 TOP VIEW VOS TRIM -IN +IN V- (CASE) H PACKAGE 8-LEAD TO-5 METAL CAN $T_{JMAX} = 150^{\circ}C$, $\theta_{JA} = 150^{\circ}C/W$, $\theta_{JC} = 45^{\circ}C/W$	 S8 PACKAGE 8-LEAD PLASTIC SO $T_{JMAX} = 150^{\circ}C$, $\theta_{JA} = 190^{\circ}C/W$
ORDER PART NUMBER	ORDER PART NUMBER	ORDER PART NUMBER
FT1007ACN8 FT1037ACN8 FT1007CN8 FT1037CN8 FT1007IN8 FT1037IN8 J8 PACKAGE LEAD CERP $T_{JMAX} = 150^{\circ}C$, $\theta_{JA} = 100^{\circ}C/W$ (J8) FT1007ACJ8 FT1037ACJ8 FT1007AMJ8 FT1037AMJ8 FT1007CJ8 FT1037CJ8 FT1007MJ8 FT1037MJ8	FT1007ACH FT1037ACH FT1007AMH FT1037AMH FT1007CH FT1037CH FT1007MH FT1037MH	FT1007CS8 FT1037CS8 FT1007IS8 FT1037IS8 S8 PART MARKING 1007 1037 1007I 1037I

Electrical Characteristics $V_S = \pm 15V$, $T_A = 25^{\circ}C$, unless otherwise noted.

SYMBOL	PARAMETER	CONDITIONS	FT1007AC/AM FT1037AC/AM			FT1007C/I/M FT1037C/I/M			UNITS
			MIN	TYP	MAX	MIN	TYP	MAX	
V_{OS}	Input Offset Voltage	(Note 2)		10	25		20	60	μV
$\frac{\Delta V_{OS}}{\Delta Time}$	Long Term Input Offset Voltage Stability	(Notes 3, 4)		0.2	1.0		0.2	1.0	$\mu V/Mo$
I_{OS}	Input Offset Current			7	30		12	50	nA
I_B	Input Bias Current			± 10	± 35		± 15	± 55	nA
e_n	Input Noise Voltage	0.1Hz to 10Hz (Notes 4, 6)		0.06	0.13		0.06	0.13	μV_{P-P}
	Input Noise Voltage Density	$f_0 = 10Hz$ (Notes 4, 5) $f_0 = 1000Hz$ (Note 4)		2.8 2.5	4.5 3.8		2.8 2.5	4.5 3.8	$nV/\sqrt{Hz}$ $nV/\sqrt{Hz}$
i_n	Input Noise Current Density	$f_0 = 10Hz$ (Notes 4, 7) $f_0 = 1000Hz$ (Notes 4, 7)		1.5 0.4	4.0 0.6		1.5 0.4	4.0 0.6	$pA/\sqrt{Hz}$ $pA/\sqrt{Hz}$

Electrical Characteristics $V_S = \pm 15V$, $T_A = 25^\circ C$, unless otherwise noted.

SYMBOL	PARAMETER	CONDITIONS	FT1007AC/AM FT1037AC/AM			FT1007C/I/M FT1037C/I/M			UNITS
			MIN	TYP	MAX	MIN	TYP	MAX	
	Input Resistance, Common Mode			7			5		G Ω
	Input Voltage Range		± 11.0	± 12.5		± 11.0	± 12.5		V
CMRR	Common Mode Rejection Ratio	$V_{CM} = \pm 11V$	117	130		110	126		dB
PSRR	Power Supply Rejection Ratio	$V_S = \pm 4V$ to $\pm 18V$	110	130		106	126		dB
A_{VOL}	Large-Signal Voltage Gain	$R_L \geq 2k$, $V_O = \pm 12V$	7.0	20.0		5.0	20.0		V/ μV
		$R_L \geq 1k$, $V_O = \pm 10V$	5.0	16.0		3.5	16.0		V/ μV
		$R_L \geq 600\Omega$, $V_O = \pm 10V$	3.0	12.0		2.0	12.0		V/ μV
V_{OUT}	Maximum Output Voltage Swing	$R_L \geq 2k$	± 13.0	± 13.8		± 12.5	± 13.5		V
		$R_L \geq 600\Omega$	± 11.0	± 12.5		± 10.5	± 12.5		V
SR	Slew Rate	$R_L \geq 2k$	1.7	2.5		1.7	2.5		V/ μs
		$A_{VOL} \geq 5$	11	15		11	15		V/ μs
GBW	Gain Bandwidth Product	$f_0 = 100kHz$ (Note 8)	5.0	8.0		5.0	8.0		MHz
		$f_0 = 10kHz$ (Note 8) ($A_{VOL} \geq 5$)	45	60		45	60		MHz
Z_O	Open-Loop Output Resistance	$V_O = 0V$, $I_O = 0$		70			70		Ω
P_D	Power Dissipation	FT1007		80	120		80	140	mW
		FT1037		80	130		85	140	mW

The ● denotes the specifications which apply over the temperature range $0^\circ C \leq T_A \leq 70^\circ C$, $V_S = \pm 15V$, unless otherwise noted.

SYMBOL	PARAMETER	CONDITIONS		FT1007AC FT1037AC			FT1007C FT1037C			UNITS
				MIN	TYP	MAX	MIN	TYP	MAX	
V_{OS}	Input Offset Voltage	(Note 2)	●		20	50		35	110	μV
$\frac{\Delta V_{OS}}{\Delta Temp}$	Average Input Offset Drift	(Note 10)	●		0.2	0.6		0.3	1.0	$\mu V/^\circ C$
I_{OS}	Input Offset Current		●		10	40		15	70	nA
I_B	Input Bias Current		●		± 14	± 45		± 20	± 75	nA
	Input Voltage Range		●	± 10.5	± 11.8		± 10.5	± 11.8		V
CMRR	Common Mode Rejection Ratio	$V_{CM} = \pm 10.5V$	●	114	126		106	120		dB
PSRR	Power Supply Rejection Ratio	$V_S = \pm 4.5V$ to $\pm 18V$	●	106	126		102	120		dB
A_{VOL}	Large-Signal Voltage Gain	$R_L \geq 2k$, $V_O = \pm 10V$	●	4.0	18.0		2.5	18.0		V/ μV
		$R_L \geq 1k$, $V_O = \pm 10V$	●	2.5	14.0		2.0	14.0		V/ μV
V_{OUT}	Maximum Output Voltage Swing	$R_L \geq 2k$	●	± 12.5	± 13.6		± 12.0	± 13.6		V
P_D	Power Dissipation		●		90	144		90	160	mW



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